## NSN 5961-01-263-2848

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View Online at https://aerobasegroup.com/nsn/5961-01-263-2848 **Inclosure Material:** Metal **Overall Length:** 1.646 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-208aa **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.650 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 repetitive peak reverse voltage and 1000.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 10.00 milliamperes forward current, average any acceptable and 10.00 milliamperes forward current, average major **Power Rating Per Characteristic:** 8.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpnp **Thread Series Designator: Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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